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Dual High Output Current, High Speed Amplifier

Preliminary Technical Data

AD8017

FEATURES

Low cost drive amplifiers provide 200mA, 10.2Vpp output. Ideal as a PC based, Customer Premise Equipment (CPE) driver in DSL applications.

Output Voltage 1.0V to the Rail into 100Ω

Low Cost

Low Power Operation

+5V to +12V Voltage Supply

7mA/amp Supply Current

Current Feedback Amplifiers

High Output Voltage and Current Drive

200mA Output Drive Current into 25Ω

500mA Short Circuit Output Drive Current

20Vp-p Differential Output Voltage, $R_L = 50\Omega$

Low Distortion

-83dBc @ 500kHz SFDR, $R_L = 100\Omega$, $V_o = 2Vp-p$

1.9nV/√Hz Voltage noise density

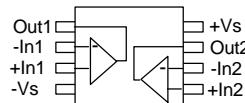
High Speed

160MHz Bandwidth (-3dB)

1500V/μs Slew Rate

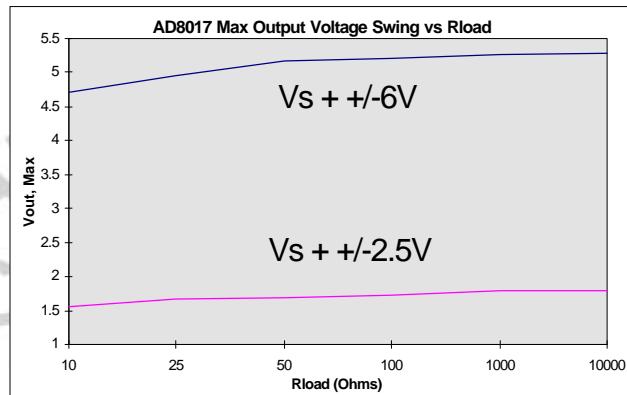
APPLICATIONS

xDSL PCI Cards
Consumer DSL Modems
Line Driver
Video Distribution



AD8017

8 Pin 'Thermal Coastline' SOIC



Low distortion, high output voltage drive, and high output current drive make the AD8017 ideal for use in low cost

Customer Premise End (CPE) equipment for ADSL, SDSL, VDSL and proprietary xDSL systems.

The AD8017 drive capability comes in a very compact form. Utilizing ADI's proprietary 'Thermal Coastline' SOIC package, the AD8017's total (static and dynamic) power on +12V supplies is easily dissipated without external heat sink, other than to place the AD8017 on a 4-layer PCB.

The AD8017 will operate over the Commercial Temperature range 0°C to +85°C.

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SPECIFICATIONS (@25°C, Vs=+/-6V, RL=100Ω, RF=RG=620Ω, unless otherwise noted)

Parameter	Conditions	AD8017			Units
		Min	Typ	Max	
DYNAMIC PERFORMANCE					
-3dB Bandwidth	G= +2, VOUT<0.4V p-p	TBD	160		MHz
0.1dB Bandwidth	VOUT<0.4V p-p		70		MHz
Large Signal Bandwidth	VOUT=4V p-p		TBD		MHz
Slew Rate	Non-Inverting, VOUT=2Vp-p, G=+2	1500		V/μs	
Rise & Fall Time	Non-Inverting, VOUT= 2Vp-p		2.6		ns
Settling Time	0.1%, VOUT= 2Vp-p		14		ns
Peaking	VOUT=0.4V p-p,<5MHz		TBD		dB
NOISE / HARMONIC PERFORMANCE					
Distortion,	VOUT= 2Vp-p				
2 nd Harmonic	500kHz, RL=100 Ω /25 Ω		-78/-71		dBc
	1MHz, RL=100 Ω /25 Ω		-76/-69		dBc
3 rd Harmonic	500kHz, RL=100 Ω /25 Ω		-105/-91		dBc
	1MHz, RL=100 Ω /25 Ω		-81/-72		dBc
IP3	500kHz, RL=100 Ω /25 Ω		TBD		dBm
IMD	500kHz, RL=100 Ω /25 Ω		TBD		dBc
MTPR	26kHz to 1.1MHz		TBD		dBc
Input Noise Voltage	f=10kHz		1.9		nV/Hz
Input Noise Current	f=10kHz (+ Inputs)		TBD		pA/Hz
Input Noise Current	f=10kHz (- Inputs)		TBD		pA/Hz
Crosstalk	f = 5MHz, G=+2		70		dB
DC PERFORMANCE					
Input Offset Voltage	Tmin-Tmax		1.5	TBD	mV
Transimpedance Gain	VOUT= 2Vp-p	TBD	800	TBD	KΩ
	Tmin-Tmax	TBD			KΩ
INPUT CHARACTERISTICS					
Input Resistance	+Input		TBD		KΩ
	-Input		TBD		KΩ
Input Capacitance	+Input		2		pF
Input Bias Current (-)	Tmin-Tmax		±10	TBD	μA
Input Bias Current (+)	Tmin-Tmax		±10	TBD	μA
CMRR	Vcm=+/-2.5V		60		dB
Input CM Voltage Range			±5.1		V
OUTPUT CHARACTERISTICS					
Output Resistance			TBD		Ω
Output Voltage Swing	RL =25Ω	TBD	±5.1		V
Output Current	RL =25 Ω	TBD	200		mA
Short-Circuit Current			500		mA
POWER SUPPLY					
Supply Current/Amp			7.0	TBD	mA
Operating Range	Tmin - Tmax		TBD		mA
Power Supply Rejection Ratio	Dual Supply	±TBD	±6.0		V
			66	TBD	dB
Operating Temperature Range		0	+85		Deg C

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SPECIFICATIONS (@25°C, Vs=+/-2.5V, RL=100Ω, RF=RG=620Ω, unless otherwise noted)

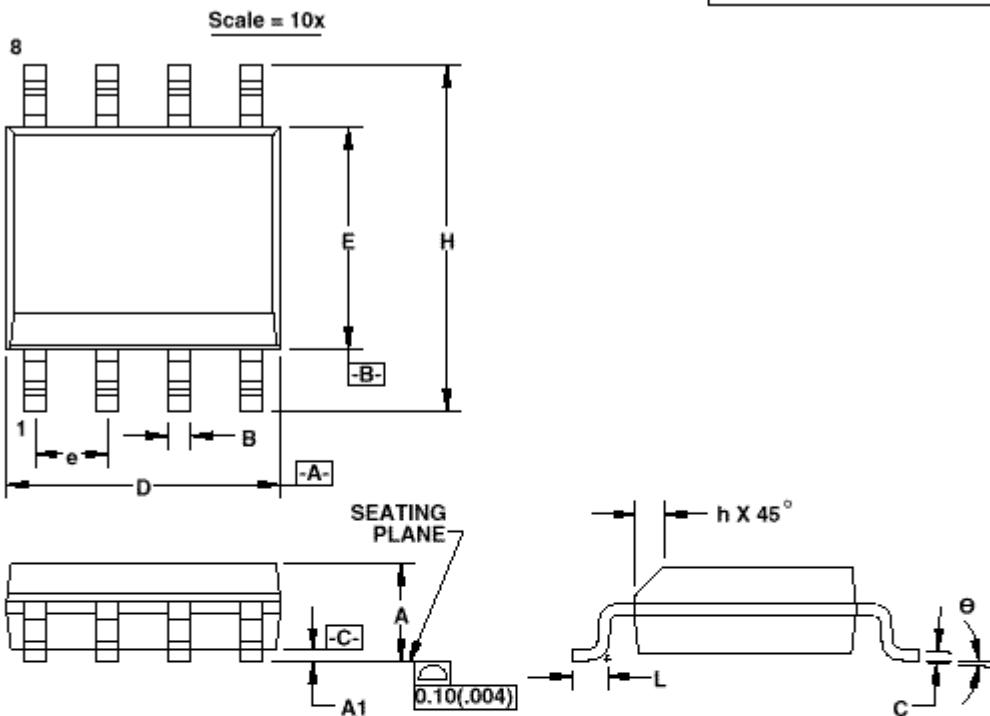
Parameter	Conditions	AD8017			
		Min	Typ	Max	Units
DYNAMIC PERFORMANCE					
-3dB Bandwidth	G= +2, VOUT<0.4V p-p	TBD	120		MHz
0.1dB Bandwidth	VOUT<0.4V p-p		TBD		MHz
Large Signal Bandwidth	VOUT=4V p-p		TBD		MHz
Slew Rate	Non-Inverting, VOUT=2Vp-p, G=+2	TBD		V/μs	
Rise & Fall Time	Non-Inverting, VOUT= 2Vp-p		1.3		ns
Settling Time	0.1%, VOUT= 2Vp-p		14		ns
Peaking	VOUT=0.4V p-p,<5MHz		TBD		dB
NOISE / HARMONIC PERFORMANCE					
Distortion,	VOUT= 2Vp-p				
2 nd Harmonic	500kHz, RL=100 Ω /25 Ω		-75/-68		dBc
	1MHz, RL=100 Ω /25 Ω		-73/-67		dBc
3 rd Harmonic	500kHz, RL=100 Ω /25 Ω		-91/-90		dBc
	1MHz, RL=100 Ω /25 Ω		-79/-79		dBc
IP3	500kHz, RL=100 Ω /25 Ω		TBD		dBm
IMD	500kHz, RL=100 Ω /25 Ω		TBD		dBc
MTPR	26kHz to 1.1MHz		TBD		dBc
Input Noise Voltage	f=10kHz		1.8		nV√Hz
Input Noise Current	f=10kHz (+ Inputs)		18.9		pA√Hz
Input Noise Current	f=10kHz (- Inputs)		17.7		pA√Hz
Crosstalk	f = 5MHz, G=+2		70		dB
DC PERFORMANCE					
Input Offset Voltage	Tmin-Tmax		1.5	TBD	mV
Transimpedance Gain	VOUT= 2Vp-p	TBD	800		KΩ
	Tmin-Tmax	TBD			KΩ
INPUT CHARACTERISTICS					
Input Resistance	+Input		TBD		KΩ
	-Input		TBD		KΩ
Input Capacitance	+Input		2		pF
Input Bias Current (-)	Tmin-Tmax		±10	TBD	μA
Input Bias Current (+)	Tmin-Tmax		±10	TBD	μA
CMRR	Vcm=+/-1.0V		60		dB
Input CM Voltage Range			±1.6		V
OUTPUT CHARACTERISTICS					
Output Resistance			TBD		Ω
Output Voltage Swing	RL =25Ω	TBD	±1.6		V
Output Current	RL =25 Ω	TBD	66		mA
Short-Circuit Current			TBD		mA
POWER SUPPLY					
Supply Current/Amp			6.6	TBD	mA
Operating Range	Tmin - Tmax		TBD		mA
Power Supply Rejection Ratio	Single Supply		+5		V
			63	TBD	dB
Operating Temperature Range		0	+85		Deg C

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MILLIMETERS		
Dimension	Min.	Max
A	1.35	1.75
A1	0.10	0.25
B	0.33	0.51
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC.	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.27
θ	0°	8°

INCHES		
Dimension	Min.	Max
A	.0532	.0688
A1	.0040	.0098
B	.013	.020
C	.0075	.0098
D	.1890	.1968
E	.1497	.1574
e	.050 BSC.	
H	.2284	.2440
h	.0099	.0196
L	.016	.050
θ	0°	8°

**Title: 8L SOIC 150 mil
Package Outline
CUSTOMER**

NOTES:

1. Controlling Dimensions are in mm.
2. All Dimensions per JEDEC Standards MS-012 AA